

| Ref # | Hits   | Search Query                                     | DBs   | Default Operator | Plurals | Time Stamp       |
|-------|--------|--|---|------------------|---------|------------------|
| S1    | 34     | ((band adj type) or (band-type)) near electrode  | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR               | ON      | 2005/08/02 10:17 |
| S2    | 23     | ((band adj type) or (band-type)) near conduct\$3 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR               | ON      | 2005/08/02 10:18 |
| S3    | 6      | ((band adj type) or (band-type)) near conductor  | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR               | ON      | 2005/08/02 10:38 |
| S4    | 6      | ((band adj type) or (band-type)) near conductive | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR               | ON      | 2005/08/02 10:29 |
| S5    | 4687   | ((band adj type) or (band-type))                 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR               | ON      | 2005/08/02 10:38 |
| S6    | 123    | S5 and wafer                                     | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR               | ON      | 2005/08/02 10:38 |
| S7    | 666304 | conductor  | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR               | ON      | 2005/08/02 10:38 |
| S8    | 73739  | bit-line or (bit adj line)                       | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR               | ON      | 2005/08/02 10:38 |
| S9    | 9239   | S7 and S8  | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR               | ON      | 2005/08/02 10:38 |
| S10   | 0      | S6 and S9  | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR               | ON      | 2005/08/02 10:39 |

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|-----|--------|-----------------------|---|----|----|------------------|
| S11 | 1      | S9 and S5             | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:45 |
| S12 | 7271   | storage adj electrode | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:46 |
| S13 | 978    | secondary adj mold    | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:46 |
| S14 | 0      | S12 and S13           | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:46 |
| S15 | 213433 | tungsten              | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:46 |
| S16 | 134565 | silicon adj nitride   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:46 |
| S17 | 112510 | polysilicon           | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:48 |
| S18 | 125092 | silicon adj oxide     | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:48 |
| S19 | 25720  | TEOS                  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:48 |
| S20 | 613    | PETEOS                | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:49 |

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|-----|--------|---------------|---|----|----|------------------|
| S21 | 285637 | insulator     | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:49 |
| S22 | 666304 | conductor     | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:49 |
| S23 | 10454  | ArF           | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:49 |
| S24 | 11899  | KrF           | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:49 |
| S25 | 6813   | S23 and S24   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:49 |
| S26 | 675    | S25 and S22   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:50 |
| S27 | 256    | S26 and S21   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:50 |
| S28 | 398545 | line and band | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:51 |
| S29 | 92     | S27 and S28   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:51 |
| S30 | 4      | S29 and S19   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:56 |

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|-----|---------|-----------------------------|---|----|----|------------------|
| S31 | 196     | diagonal near electrode     | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:57 |
| S32 | 0       | (zg adj zag) near electrode | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 10:57 |
| S33 | 51      | S31 and semiconductor       | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:23 |
| S34 | 1       | 10/731931                   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 07:57 |
| S35 | 1       | 09/426108                   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:23 |
| S36 | 7       | "6344379"                   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:26 |
| S37 | 1486212 | electrode                   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:26 |
| S38 | 399468  | branch                      | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:26 |
| S39 | 0       | S37 adj S36                 | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:26 |
| S40 | 395     | S37 adj S38                 | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:31 |

|     |         |                       |   |    |    |                  |
|-----|---------|-----------------------|---|----|----|------------------|
| S41 | 688     | S37 near S38          | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:26 |
| S42 | 520637  | space near between    | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:31 |
| S43 | 3124856 | increase              | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:31 |
| S44 | 3074    | S43 near "44"         | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:31 |
| S45 | 1486212 | electrodes            | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:31 |
| S46 | 439     | S44 and S45           | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:32 |
| S47 | 7       | S44 near S45          | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:33 |
| S48 | 779437  | array                 | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:33 |
| S49 | 12782   | S45 near S48          | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:33 |
| S50 | 3111    | S49 and semiconductor | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:34 |

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|-----|---------|--------------|---|----|----|------------------|
| S51 | 139189  | diagonal     | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:34 |
| S52 | 229     | S51 and S50  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:42 |
| S53 | 107441  | DRAM         | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:55 |
| S54 | 1486212 | electrode    | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:42 |
| S55 | 1603104 | pattern      | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:42 |
| S56 | 27135   | S54 near S55 | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:43 |
| S57 | 847     | S56 and S53  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:44 |
| S58 | 139189  | diagonal     | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:44 |
| S59 | 20      | S57 and S58  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:44 |
| S60 | 702     | S53 and S25  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:55 |

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|-----|-----|---------------|---|----|----|------------------|
| S61 | 118 | S60 and S16   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:56 |
| S62 | 66  | S61 and S17   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 12:30 |
| S63 | 57  | S62 and S18   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:56 |
| S64 | 19  | S63 and S19   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 12:06 |
| S65 | 0   | S64 and S20   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:56 |
| S66 | 5   | S64 and S21   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:57 |
| S67 | 2   | S64 and S22   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 11:57 |
| S68 | 3   | 09/904591     | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 12:30 |
| S69 | 2   | 09/903580     | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/02 12:30 |
| S70 | 2   | "6403413".pn. | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 07:57 |

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|-----|--------|---------------------|---|----|----|------------------|
| S71 | 134829 | silicon adj nitride | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:12 |
| S72 | 112701 | polysilicon         | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:12 |
| S73 | 125324 | silicon adj oxide   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:12 |
| S74 | 10479  | ArF                 | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:12 |
| S75 | 11926  | KrF                 | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:12 |
| S76 | 6830   | S74 and S75         | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:12 |
| S77 | 107631 | DRAM                | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:12 |
| S78 | 702    | S77 and S76         | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:12 |
| S79 | 118    | S78 and S71         | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:12 |
| S80 | 66     | S79 and S72         | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:12 |

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|-----|---------|----------------------------|---|----|----|------------------|
| S81 | 57      | S80 and S73                | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:16 |
| S82 | 5186    | polysilicon near electrode | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:17 |
| S83 | 1437981 | wide                       | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:17 |
| S84 | 1699340 | width                      | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:17 |
| S85 | 336     | "113" near (S83 or S84)    | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:24 |
| S86 | 1487064 | electrode                  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:25 |
| S87 | 4275    | extentions                 | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:25 |
| S88 | 5       | S86 near S87               | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:29 |
| S89 | 3475814 | contact                    | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:29 |
| S90 | 1547367 | semiconductor              | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:29 |

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|------|--------|---------------------------------|---|----|----|------------------|
| S91  | 392333 | S89 and S90                     | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:30 |
| S92  | 3896   | S91 and (storage adj electrode) | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:31 |
| S93  | 122623 | S92 ana DRAM                    | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:31 |
| S94  | 2186   | S92 and DRAM                    | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:31 |
| S95  | 1589   | S94 and polysilicon             | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:31 |
| S96  | 1589   | S95 and contact                 | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:32 |
| S97  | 788    | S96 and shape                   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:32 |
| S98  | 184    | S97 and stack                   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 14:59 |
| S99  | 2      | "6381165".pn.                   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 15:01 |
| S100 | 2      | "6885052".pn.                   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 15:04 |

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|----------|---------|------------------------|---|----|----|------------------|
| S10<br>1 | 2       | "6492701".pn.          | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 15:09 |
| S10<br>2 | 1       | 10/731931              | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 15:10 |
| S10<br>3 | 0       | ("2004/0127050").URPN. | USPAT   | OR | ON | 2005/08/04 15:10 |
| S10<br>4 | 554204  | electrode nead mold    | USPAT   | OR | ON | 2005/08/04 15:10 |
| S10<br>5 | 215016  | mold                   | USPAT   | OR | ON | 2005/08/04 15:11 |
| S10<br>6 | 2795    | storage adj electrode  | USPAT   | OR | ON | 2005/08/04 15:11 |
| S10<br>7 | 2       | S106 near S105         | USPAT   | OR | ON | 2005/08/04 15:12 |
| S10<br>8 | 76014   | etch                   | USPAT   | OR | ON | 2005/08/04 15:12 |
| S10<br>9 | 855328  | etch or remove         | USPAT   | OR | ON | 2005/08/04 15:13 |
| S11<br>0 | 2817964 | form                   | USPAT   | OR | ON | 2005/08/04 15:13 |
| S11<br>1 | 4115    | S109 near S110         | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 15:13 |
| S11<br>2 | 1       | S111 near S106         | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 15:14 |
| S11<br>3 | 914     | molded near electrode  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 15:14 |
| S11<br>4 | 132     | S113 and semiconductor | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 15:19 |

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|----------|--------|--------------------------------------|---|----|----|------------------|
| S11<br>5 | 0      | S113 and semiconducto<br>45 and DRAM | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 15:19 |
| S11<br>6 | 4      | S114 and DRAM                        | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 16:04 |
| S11<br>7 | 2      | 09/920927                            | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 16:10 |
| S11<br>8 | 4      | 09/749463                            | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 17:50 |
| S11<br>9 | 12036  | hard adj mask                        | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 17:50 |
| S12<br>0 | 134829 | silicon adj nitride                  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 17:50 |
| S12<br>1 | 420    | S119 near S120                       | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 17:51 |
| S12<br>2 | 24     | S119 near S120.ab.                   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2005/08/04 17:51 |